



High power cycling capability  
Low on-state and switching losses  
Designed for traction and industrial applications

## Phase Control Thyristor Type T123-320-18

Mean on-state current	$I_{TAV}$		320 A		
Repetitive peak off-state voltage	$V_{DRM}$		1000 ÷ 1800 V		
Repetitive peak reverse voltage	$V_{RRM}$				
Turn-off time	$t_q$		125 $\mu$ s		
$V_{DRM}, V_{RRM}, V$	1000	1200	1400	1600	1800
Voltage code	10	12	14	16	18
$T_j, ^\circ C$	-60 ÷ 125				

### MAXIMUM ALLOWABLE RATINGS

Symbols and parameters		Units	Values	Test conditions	
<b>ON-STATE</b>					
$I_{TAV}$	Mean on-state current	A	320 350	$T_c=89^\circ C$ , Double side cooled $T_c=85^\circ C$ , Double side cooled 180° half-sine wave; 50 Hz	
$I_{TRMS}$	RMS on-state current	A	502	$T_c=89^\circ C$ , Double side cooled 180° half-sine wave; 50 Hz	
$I_{TSM}$	Surge on-state current	kA	5.0 5.8	$T_j=T_{j\ max}$ $T_j=25^\circ C$	180° half-sine wave; 50 Hz ( $t_p=10\ ms$ ); single pulse; $V_D=V_R=0\ V$ ; Gate pulse: $I_G=2\ A$ ; $t_{GP}=50\ \mu s$ ; $di_G/dt \geq 1\ A/\mu s$
			6.0 6.9	$T_j=T_{j\ max}$ $T_j=25^\circ C$	180° half-sine wave; 60 Hz ( $t_p=8.3\ ms$ ); single pulse; $V_D=V_R=0\ V$ ; Gate pulse: $I_G=2\ A$ ; $t_{GP}=50\ \mu s$ ; $di_G/dt \geq 1\ A/\mu s$
$I^2t$	Safety factor	$A^2s \cdot 10^3$	125 165	$T_j=T_{j\ max}$ $T_j=25^\circ C$	180° half-sine wave; 50 Hz ( $t_p=10\ ms$ ); single pulse; $V_D=V_R=0\ V$ ; Gate pulse: $I_G=2\ A$ ; $t_{GP}=50\ \mu s$ ; $di_G/dt \geq 1\ A/\mu s$
			145 195	$T_j=T_{j\ max}$ $T_j=25^\circ C$	180° half-sine wave; 60 Hz ( $t_p=8.3\ ms$ ); single pulse; $V_D=V_R=0\ V$ ; Gate pulse: $I_G=2\ A$ ; $t_{GP}=50\ \mu s$ ; $di_G/dt \geq 1\ A/\mu s$
<b>BLOCKING</b>					
$V_{DRM}, V_{RRM}$	Repetitive peak off-state and Repetitive peak reverse voltages	V	1000 ÷ 1800	$T_{j\ min} < T_j < T_{j\ max}$ ; 180° half-sine wave; 50 Hz; Gate open	
$V_{DSM}, V_{RSM}$	Non-repetitive peak off-state and Non-repetitive peak reverse voltages	V	1100 ÷ 1900	$T_{j\ min} < T_j < T_{j\ max}$ ; 180° half-sine wave; 50 Hz; single pulse; Gate open	
$V_D, V_R$	Direct off-state and Direct reverse voltages	V	$0.75 \cdot V_{DRM}$ $0.75 \cdot V_{RRM}$	$T_j=T_{j\ max}$ ; Gate open	

<b>TRIGGERING</b>				
$I_{FGM}$	Peak forward gate current	A	5	$T_j = T_{j\ max}$
$V_{RGM}$	Peak reverse gate voltage	V	5	
$P_G$	Gate power dissipation	W	3	$T_j = T_{j\ max}$ for DC gate current
<b>SWITCHING</b>				
$(di_T/dt)_{crit}$	Critical rate of rise of on-state current non-repetitive (f=1 Hz)	A/ $\mu$ s	250	$T_j = T_{j\ max}; V_D = 0.67 \cdot V_{DRM}; I_{TM} = 2 I_{TAV};$ Gate pulse: $I_G = 2$ A; $t_{GP} = 50 \mu$ s; $di_G/dt \geq 1$ A/ $\mu$ s
<b>THERMAL</b>				
$T_{stg}$	Storage temperature	$^{\circ}$ C	-60 ÷ 125	
$T_j$	Operating junction temperature	$^{\circ}$ C	-60 ÷ 125	
<b>MECHANICAL</b>				
F	Mounting force	kN	5.0 ÷ 7.0	
a	Acceleration	m/s <sup>2</sup>	50 100	Device unclamped Device clamped

## CHARACTERISTICS

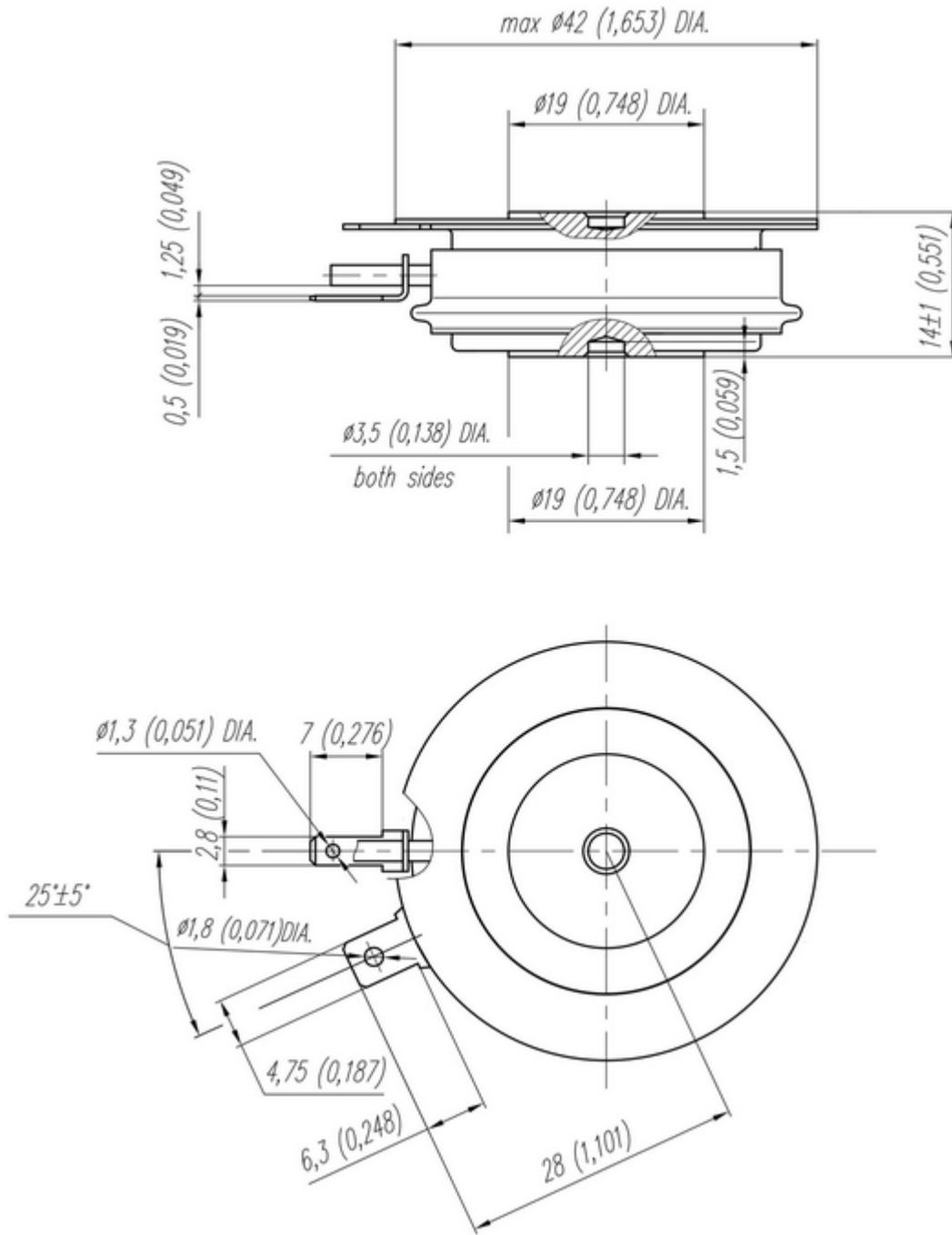
Symbols and parameters		Units	Values	Conditions	
<b>ON-STATE</b>					
$V_{TM}$	Peak on-state voltage, max	V	1.75	$T_j = 25 \text{ }^{\circ}\text{C}; I_{TM} = 1005$ A	
$V_{T(TO)}$	On-state threshold voltage, max	V	0.90	$T_j = T_{j\ max};$	
$r_T$	On-state slope resistance, max	m $\Omega$	0.850	$0.5 \pi I_{TAV} < I_T < 1.5 \pi I_{TAV}$	
$I_L$	Latching current, max	mA	500	$T_j = 25 \text{ }^{\circ}\text{C}; V_D = 12$ V; Gate pulse: $I_G = 2$ A; $t_{GP} = 50 \mu$ s; $di_G/dt \geq 1$ A/ $\mu$ s	
$I_H$	Holding current, max	mA	250	$T_j = 25 \text{ }^{\circ}\text{C};$ $V_D = 12$ V; Gate open	
<b>BLOCKING</b>					
$I_{DRM}, I_{RRM}$	Repetitive peak off-state and Repetitive peak reverse currents, max	mA	50	$T_j = T_{j\ max};$ $V_D = V_{DRM}; V_R = V_{RRM}$	
$(dv_D/dt)_{crit}$	Critical rate of rise of off-state voltage <sup>1)</sup> , min	V/ $\mu$ s	1000	$T_j = T_{j\ max};$ $V_D = 0.67 \cdot V_{DRM};$ Gate open	
<b>TRIGGERING</b>					
$V_{GT}$	Gate trigger direct voltage, max	V	4.00	$T_j = T_{j\ min}$ $T_j = 25 \text{ }^{\circ}\text{C}$	$V_D = 12$ V; $I_D = 3$ A; Direct gate current
			2.50		
$I_{GT}$	Gate trigger direct current, max	mA	2.00	$T_j = T_{j\ max}$	
			400	$T_j = T_{j\ min}$	
			250	$T_j = 25 \text{ }^{\circ}\text{C}$	
$V_{GD}$	Gate non-trigger direct voltage, min	V	200	$T_j = T_{j\ max}$	
			0.25	$V_D = 0.67 \cdot V_{DRM};$	
$I_{GD}$	Gate non-trigger direct current, min	mA	10.00	Direct gate current	
<b>SWITCHING</b>					
$t_{gd}$	Delay time	$\mu$ s	2.00	$T_j = 25 \text{ }^{\circ}\text{C}; V_D = 0.4 \cdot V_{DRM}; I_{TM} = I_{TAV};$ Gate pulse: $I_G = 2$ A; $t_{GP} = 50 \mu$ s; $di_G/dt \geq 1$ A/ $\mu$ s	
$t_q$	Turn-off time <sup>2)</sup> , max	$\mu$ s	125	$dv_D/dt = 50$ V/ $\mu$ s; $T_j = T_{j\ max}; I_{TM} = I_{TAV};$ $di_R/dt = -10$ A/ $\mu$ s; $V_R = 100$ V; $V_D = 0.67 \cdot V_{DRM}$	
$Q_{rr}$	Total recovered charge, max	$\mu$ C	700	$T_j = T_{j\ max}; I_{TM} = 320$ A;	
$t_{rr}$	Reverse recovery time, max	$\mu$ s	16	$di_R/dt = -10$ A/ $\mu$ s;	
$I_{rrM}$	Peak reverse recovery current, max	A	88	$V_R = 100$ V	

<b>THERMAL</b>					
$R_{thjc}$	Thermal resistance, junction to case, max	°C/W	0.070	Direct current	Double side cooled
$R_{thjc-A}$			0.154		Anode side cooled
$R_{thjc-K}$			0.126		Cathode side cooled
$R_{thck}$	Thermal resistance, case to heatsink, max	°C/W	0.010	Direct current	
<b>MECHANICAL</b>					
w	Weight, typ	g	70		
$D_s$	Surface creepage distance	mm (inch)	7.94 (0.313)		
$D_a$	Air strike distance	mm (inch)	5.00 (0.197)		

### **PART NUMBERING GUIDE**

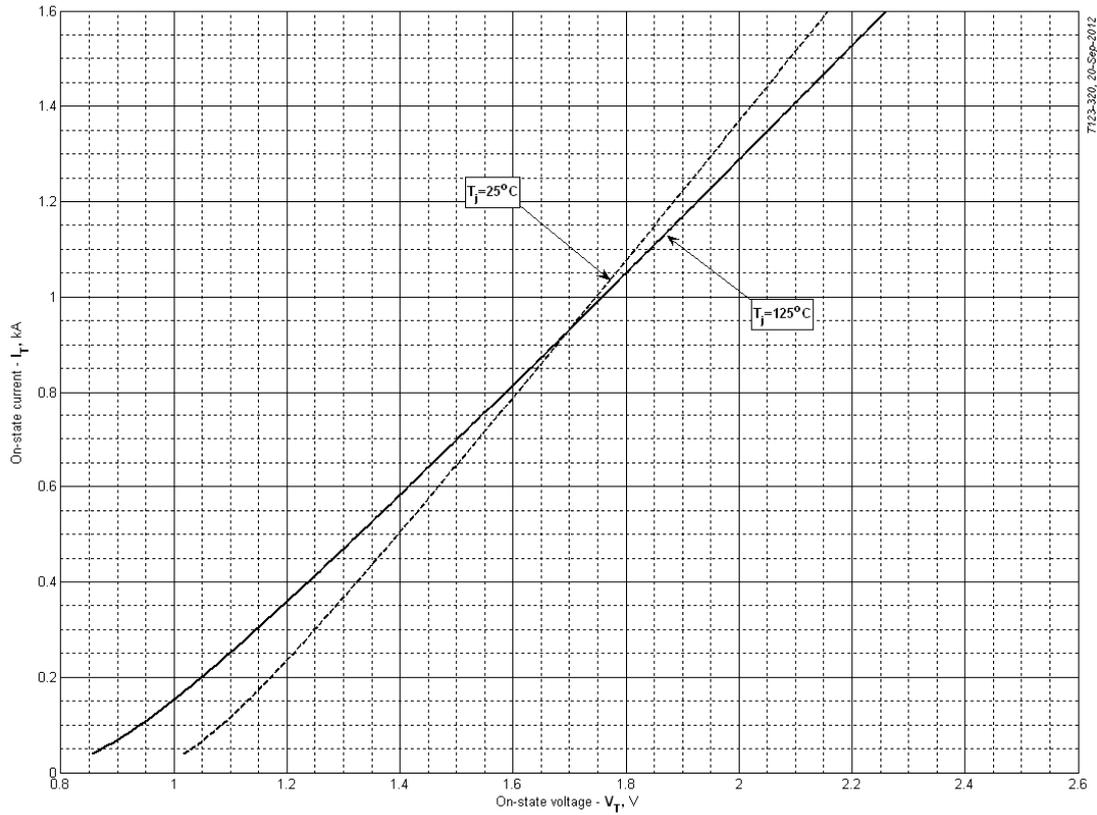
T	123	320	18	N
1	2	3	4	5

1. Phase Control Thyristor
2. Design version
3. Mean on-state current, A
4. Voltage code
5. Ambient conditions: N – normal; T – tropical



All dimensions in millimeters (inches)

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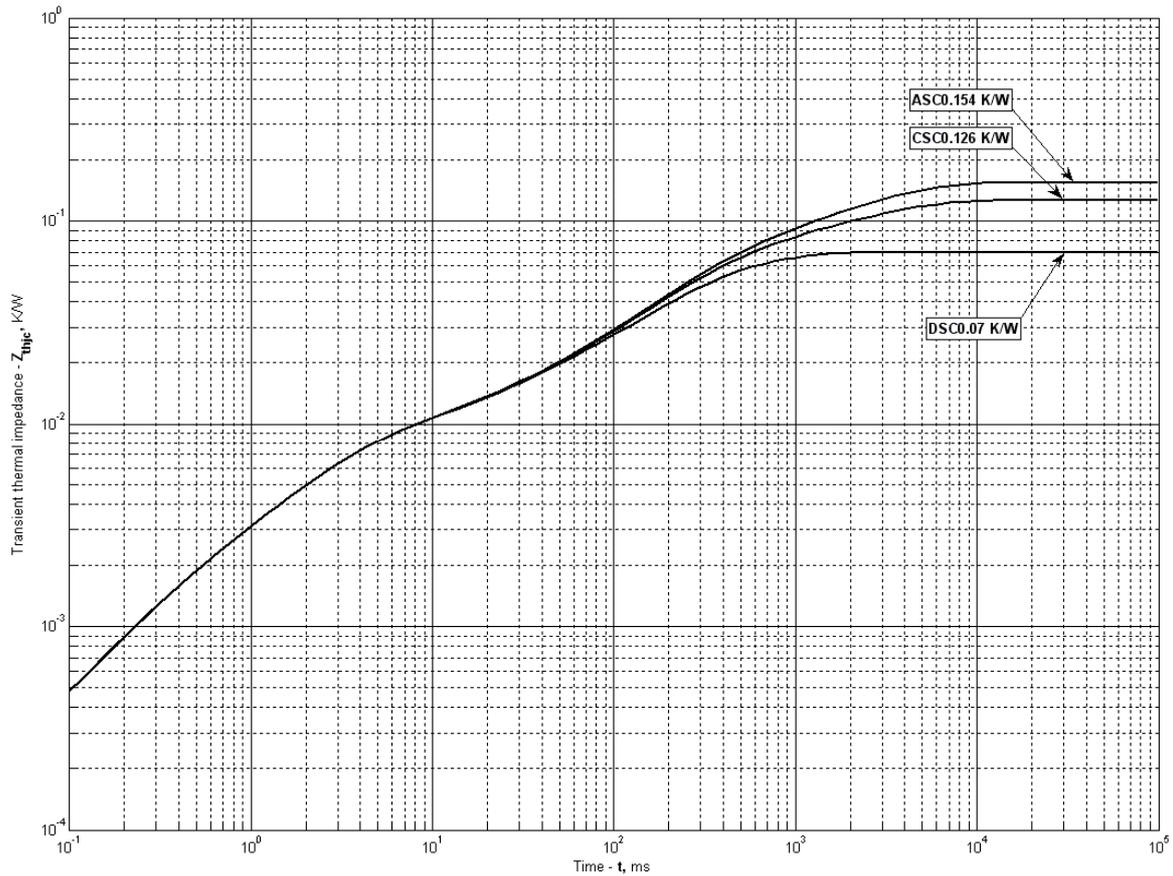
**Fig 1 – On-state characteristics of Limit device**

Analytical function for On-state characteristic:

$$V_T = A + B \cdot i_T + C \cdot \ln(i_T + 1) + D \cdot \sqrt{i_T}$$

	Coefficients for max curves	
	$T_j = 25^\circ\text{C}$	$T_j = T_{j\text{max}}$
<b>A</b>	0.938422	0.753026
<b>B</b>	0.639295	0.778347
<b>C</b>	-0.224382	-0.299678
<b>D</b>	0.324688	0.433643

**On-state characteristic model (see Fig. 1)**



**Fig 2 – Transient thermal impedance**

Analytical function for Transient thermal impedance junction to case  $Z_{thjc}$  for DC:

$$Z_{thjc} = \sum_{i=1}^n R_i \left( 1 - e^{-\frac{t}{\tau_i}} \right)$$

Where  $i = 1$  to  $n$ ,  $n$  is the number of terms in the series.

$t$  = Duration of heating pulse in seconds.

$Z_{thjc}$  = Thermal resistance at time  $t$ .

$R_i$  = Amplitude of  $p_{th}$  term.

$\tau_i$  = Time constant of  $r_{th}$  term.

DC Double side cooled

$i$	1	2	3	4	5	6
$R_i$ K/W	0.03233	0.02226	0.005231	0.002739	0.006738	0.0006988
$\tau_i$ s	0.2392	0.533	0.1478	0.01499	0.002749	0.0002969

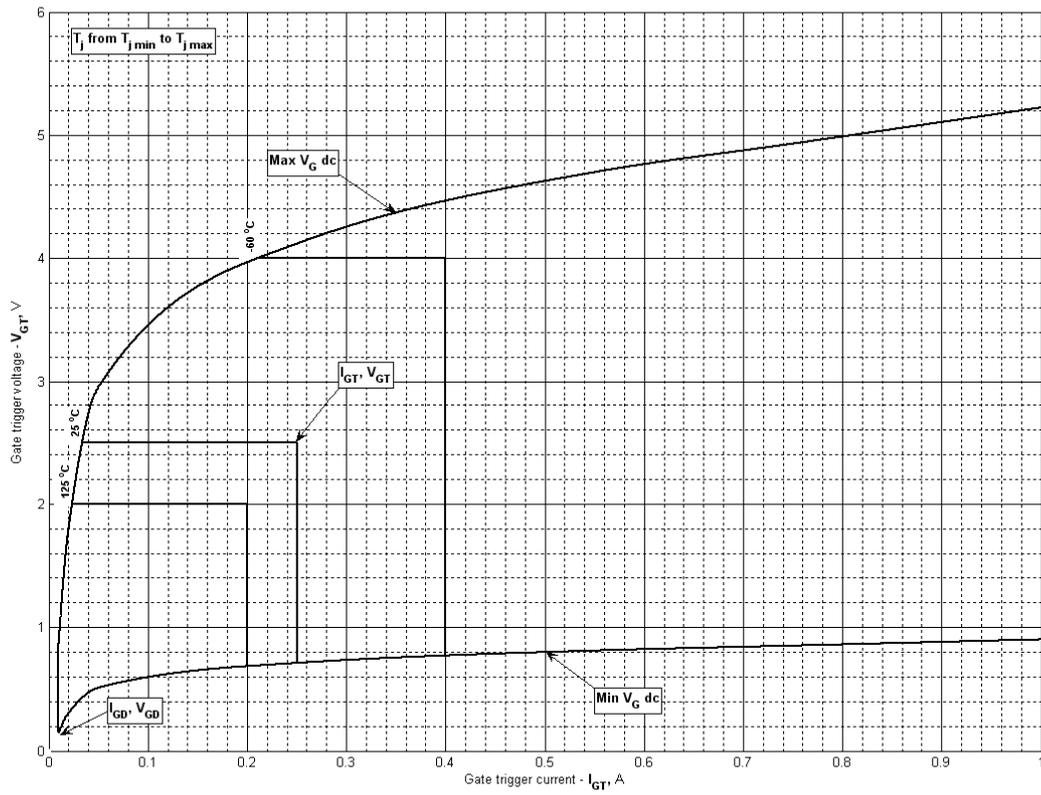
DC Anode side cooled

$i$	1	2	3	4	5	6
$R_i$ K/W	0.08459	0.02327	0.002598	0.006598	0.0006736	0.03694
$\tau_i$ s	2.653	0.5669	0.01311	0.00269	0.0002871	0.2416

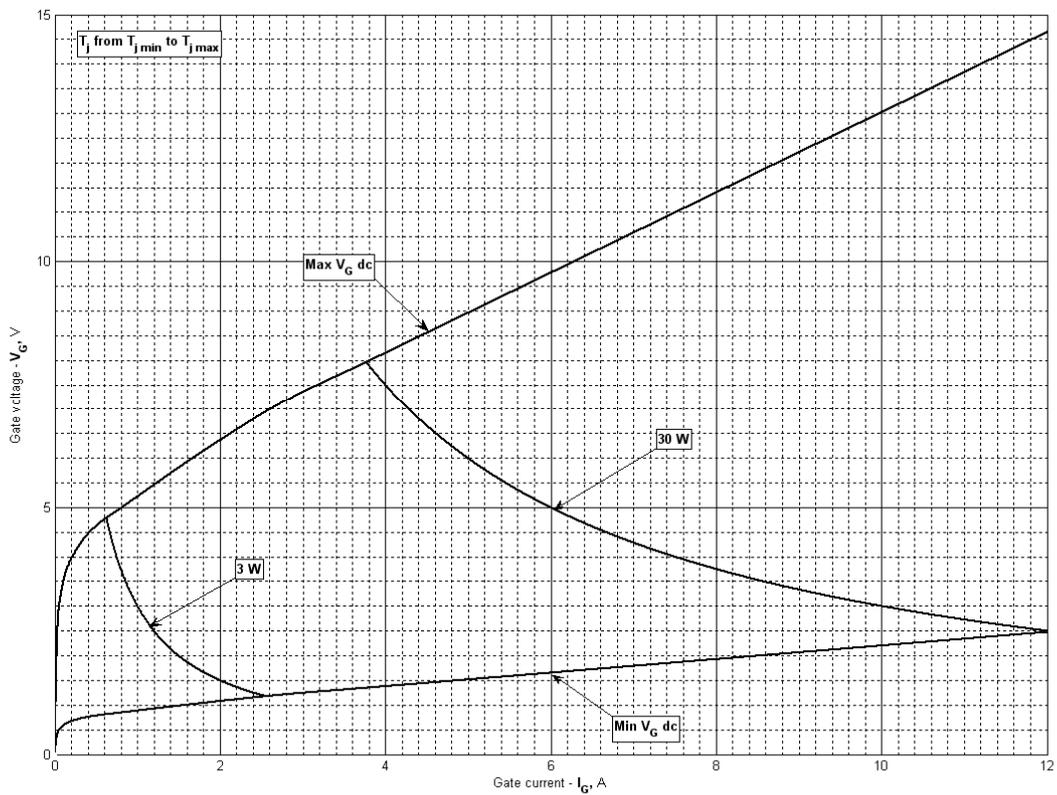
DC Cathode side cooled

$i$	1	2	3	4	5	6
$R_i$ K/W	0.05654	0.03706	0.002638	0.006637	0.0006786	0.02303
$\tau_i$ s	2.653	0.2338	0.01361	0.002704	0.000289	0.5476

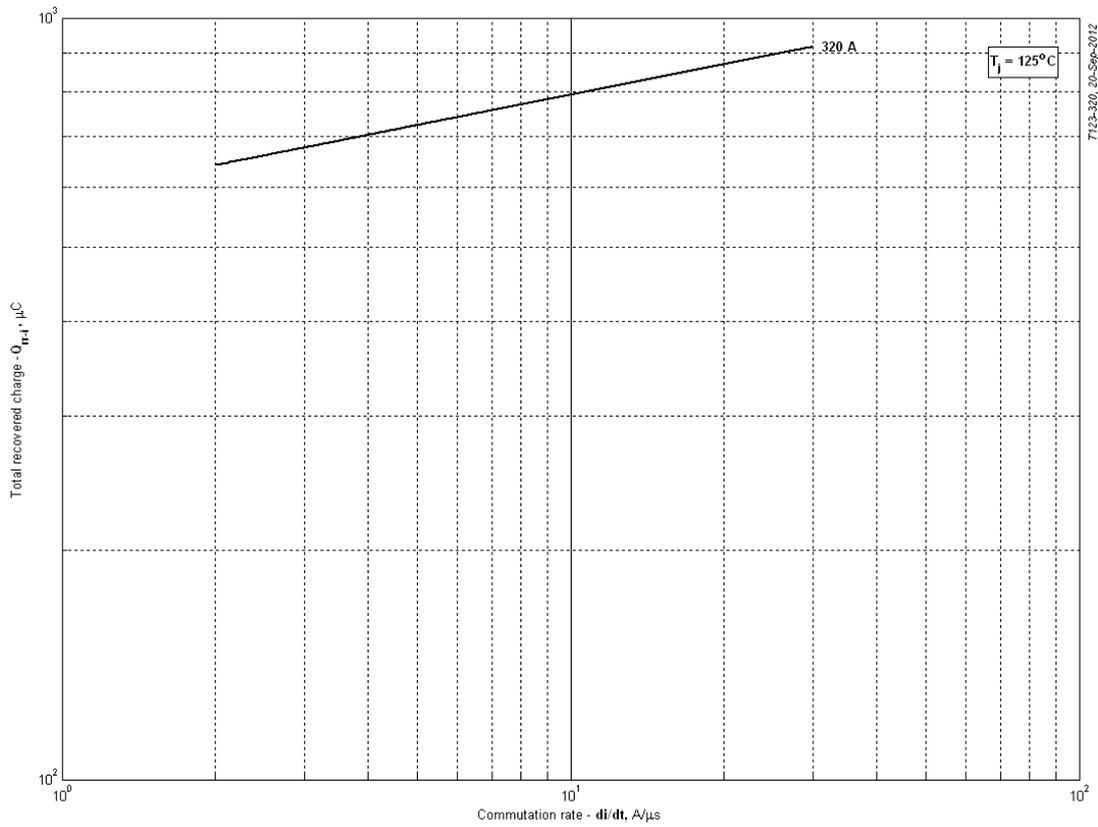
**Transient thermal impedance junction to case  $Z_{thjc}$  model (see Fig. 2)**



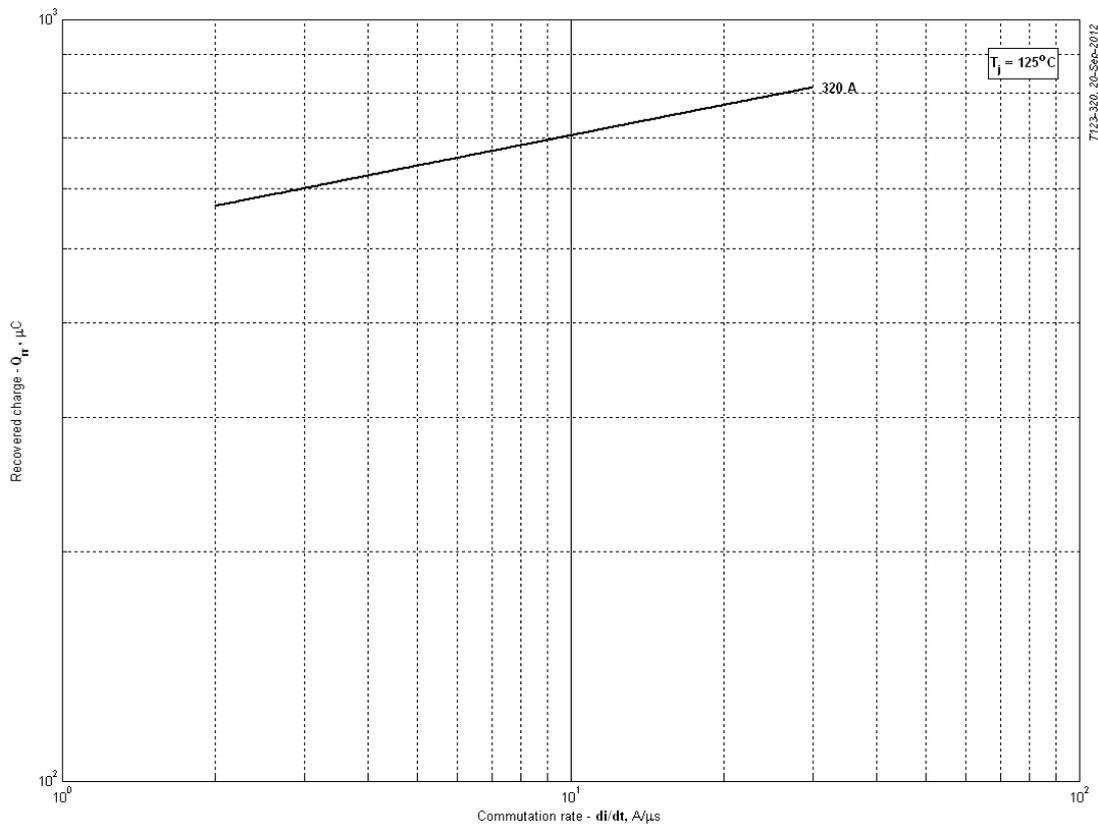
**Fig 3 – Gate characteristics – Trigger limits**



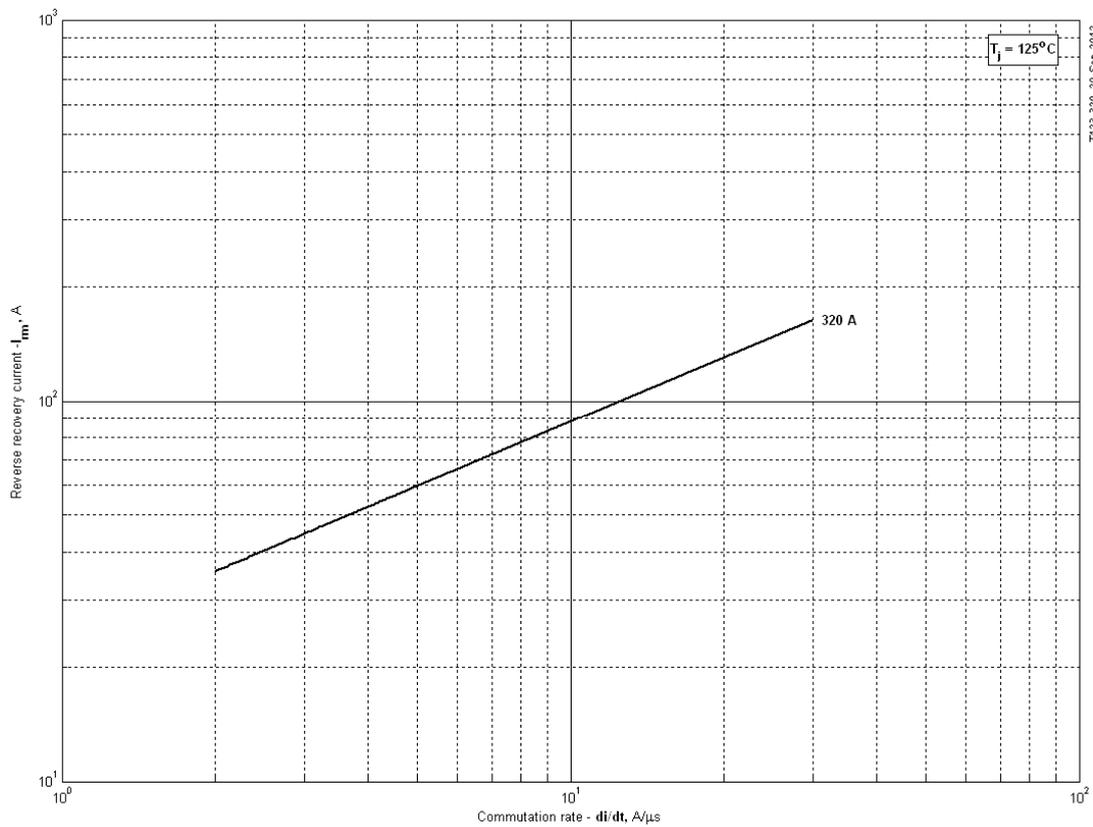
**Fig 4 - Gate characteristics –Power curves**



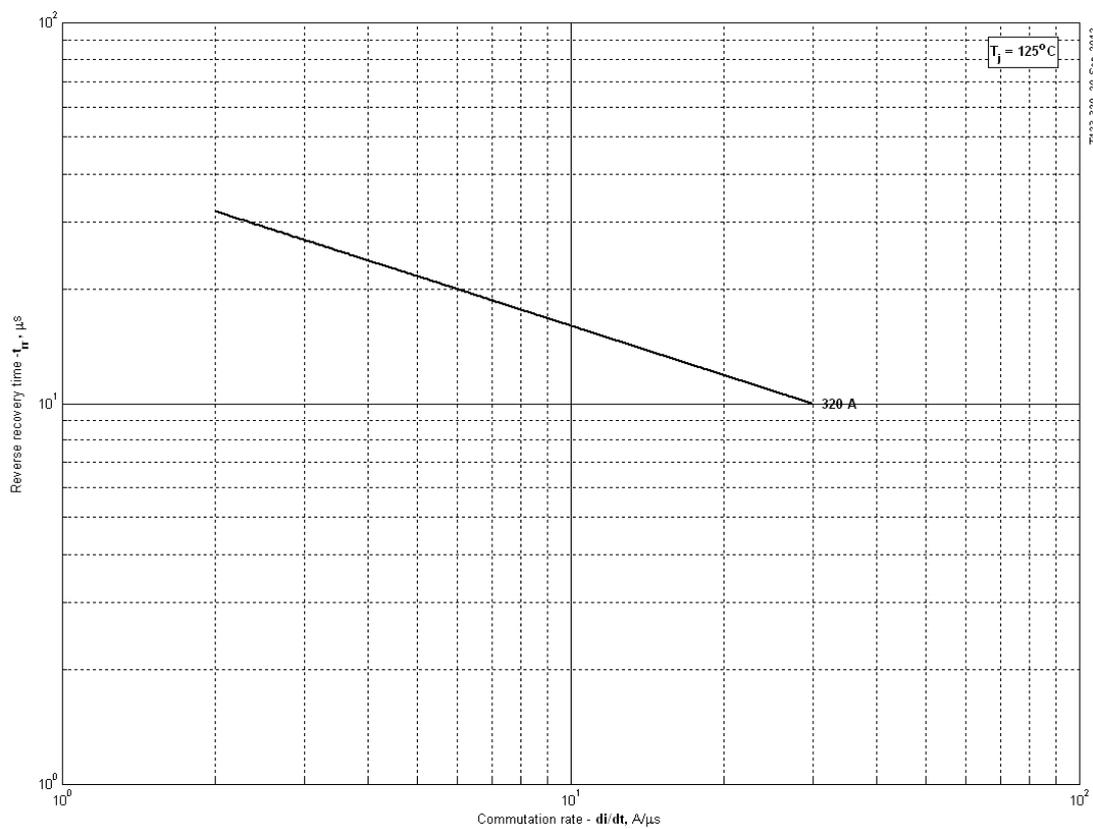
**Fig 5 – Total recovered charge,  $Q_{rr-i}$  (integral)**



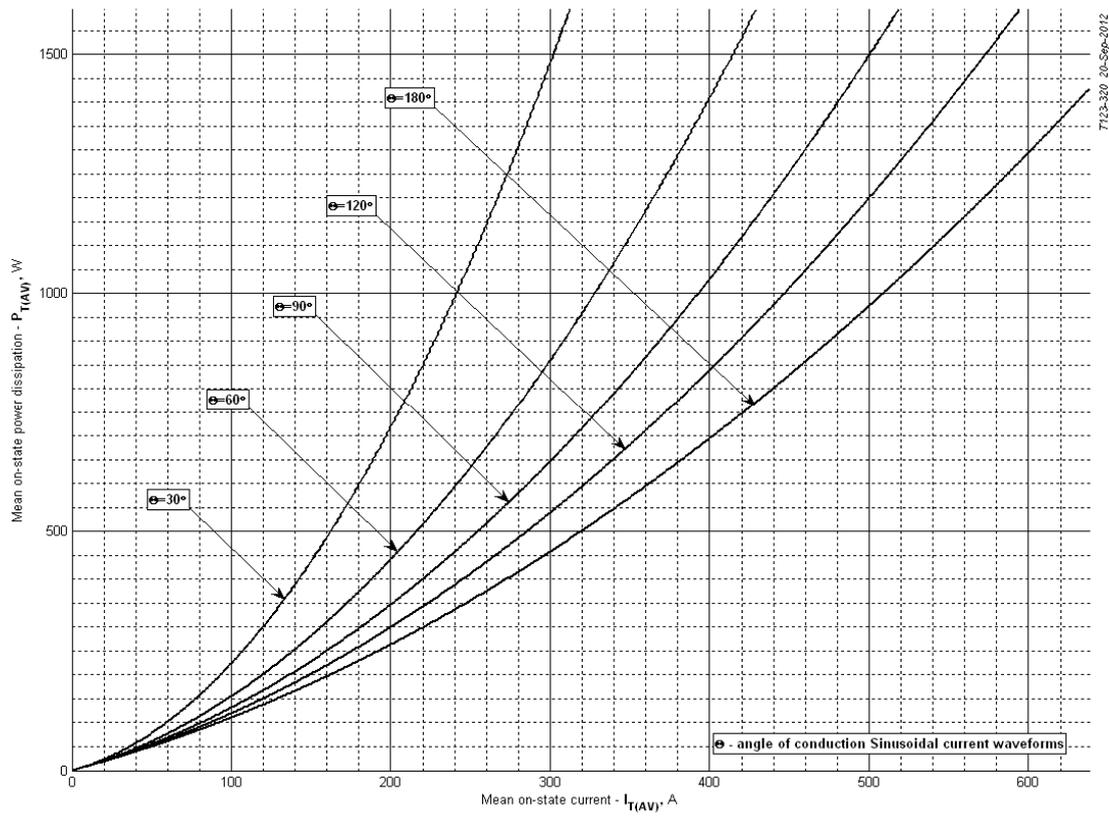
**Fig 6 - Recovered charge,  $Q_{rr}$  (linear)**



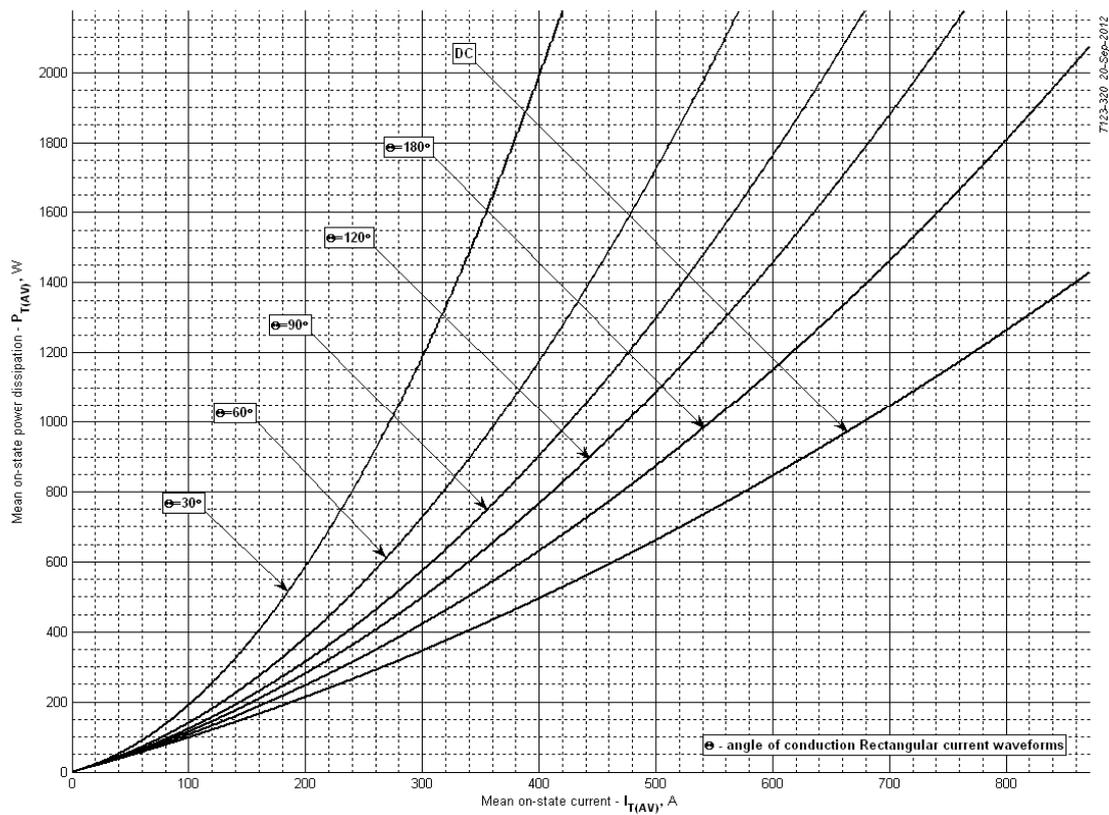
**Fig 7 – Peak reverse recovery current,  $I_{rm}$**



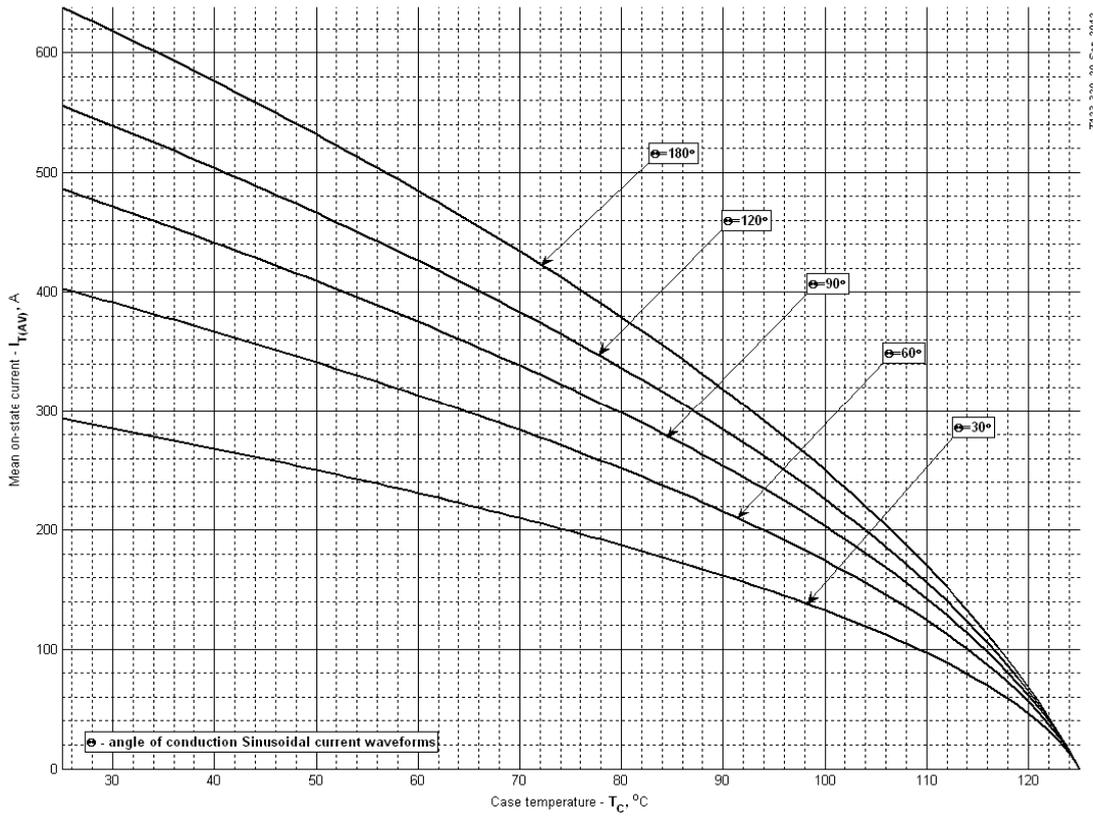
**Fig 8 – Maximum recovery time,  $t_{rr}$  (linear)**



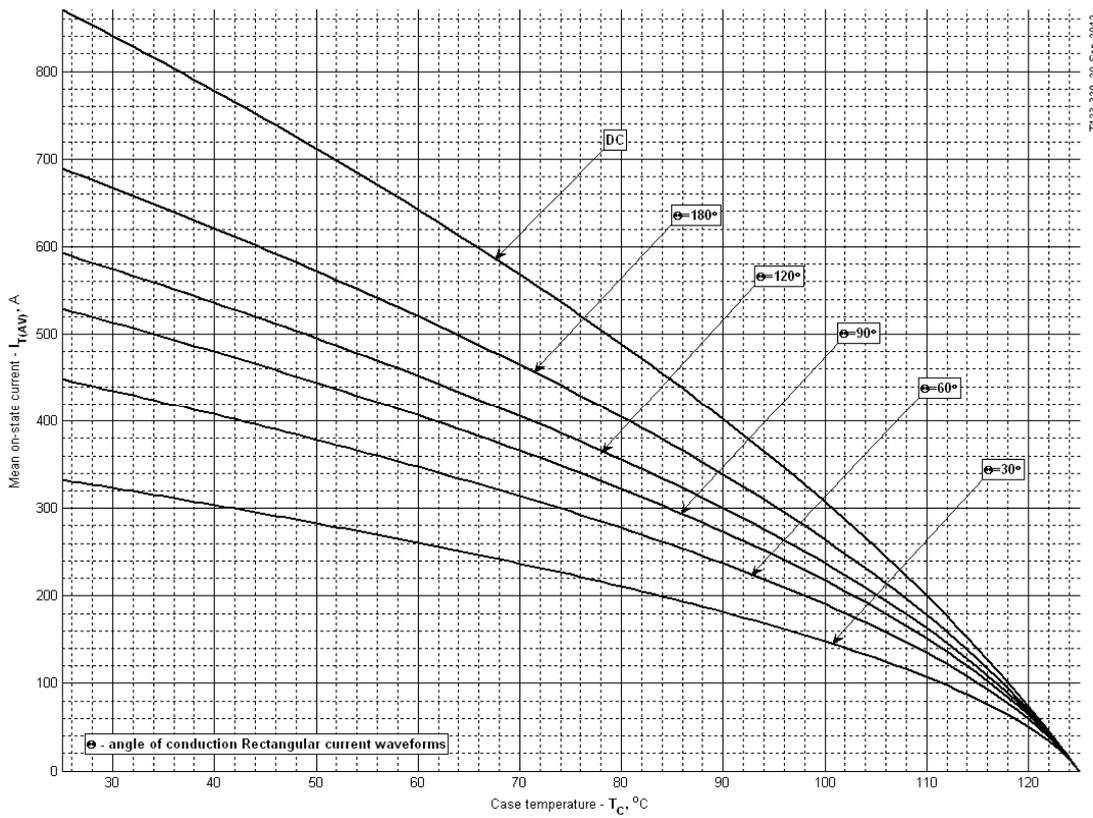
**Fig 9 – On-state power loss (sinusoidal current waveforms)**



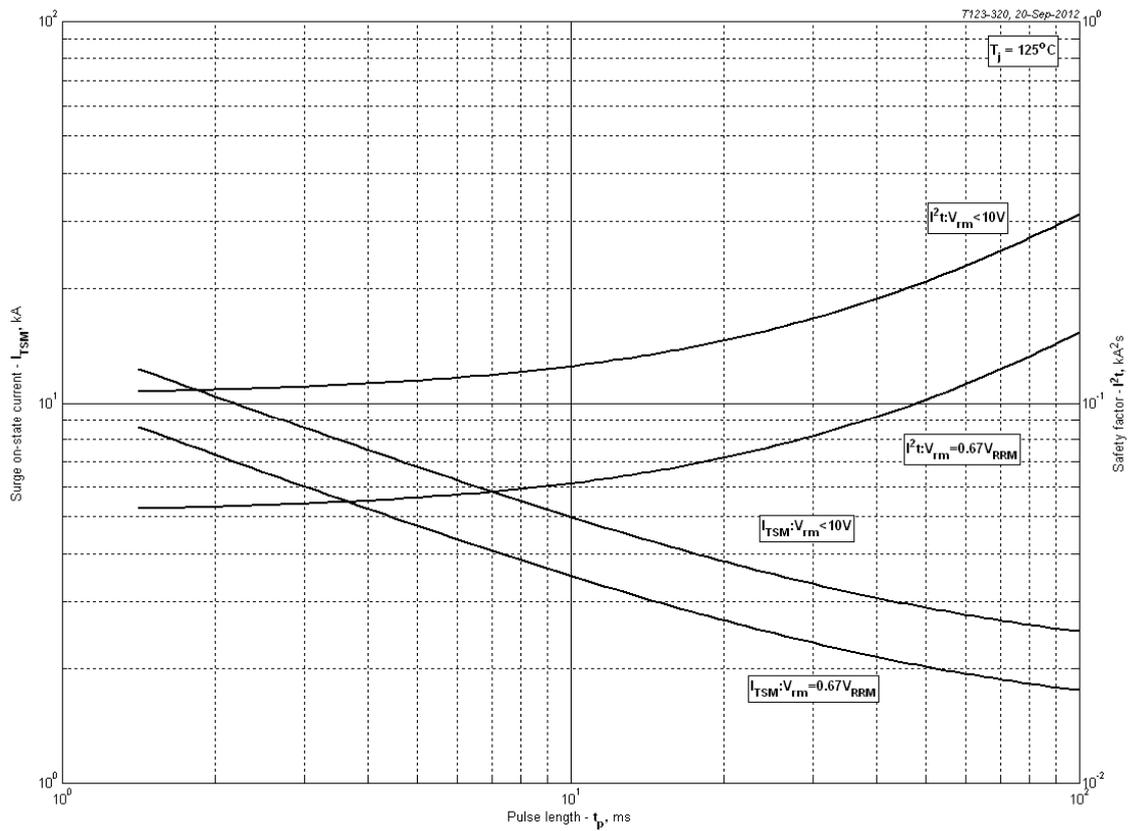
**Fig 10 – On-state power loss (rectangular current waveforms)**



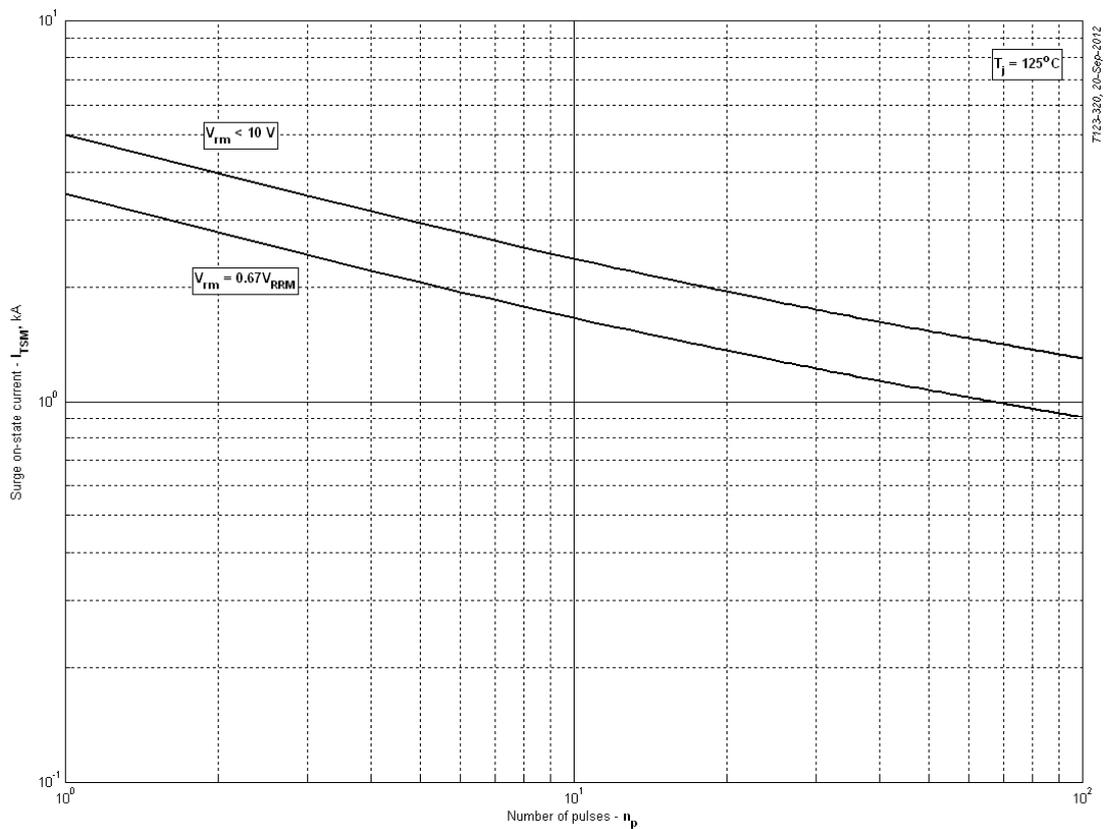
**Fig 11 – Maximum case temperature DSC (sinusoidal current waveforms)**



**Fig 12 – Maximum case temperature DSC (rectangular current waveforms)**



**Fig 13 – Maximum surge and  $I^2t$  ratings**



**Fig 14 – Maximum surge ratings**